

Two High Performance and Low Power Serial Communication Interfaces for On-chip Interconnects

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Abstract: This paper presents two novel methods for on-chip serial communication whereby the clocks of the transmitter and the receiver are generated with two separate ring oscillators. These oscillators are identical although they can have some a small frequency difference. In the first method, a strobe line, which toggles exactly once with every frame of n -bit data, is used to activate the oscillators. Local counters are used to count the number of bits in the data frame and to stop the local oscillators when the frame is processed. In the second method, a single physical line is used to transmit both data and (in-band) control information, further reducing the power dissipation. The data transmission is controlled by the output of a starter flip-flop, indicating the empty/full status of an input buffer whereas the data reception is controlled by decoding a ‘1’ start bit and a ‘0’ end bit which have been added to the n -bit data word to form a frame. Our circuit simulation results demonstrate that both communication methods result in high bandwidth and low power dissipation.

Keywords: Low-Power Communication; Chips Communication; Serial Communication; Metastability Error.

I. Introduction

While gate delays scale down with migration to technology nodes with smaller minimum feature sizes, delays of global wires typically increase or at best remain constant (if an appropriate number of repeaters are inserted on the wires). In addition, although the computation energy cost is decreasing, the communication energy cost is increasing. In a 50nm CMOS process technology, the chip die will be about 22mm on each side with a global wire delay of up to 6–10 clock cycles [1]-[3]. The major problems caused by the interconnection wires in these technologies include the complexity of wiring up components on the chip, the cross talk noise, the difficulty of achieving global synchronization, the scalability problems, and the transmission bandwidth limitation [2]-[5]. As a result, Network-on-Chip (NoC) have recently been proposed to reduce the wiring complexity in the point-to-point interconnection and solve the scalability problems that are caused by the widely popular bus-based SoC communication strategies [2][3][5].

The NoC's comprise of local synchronous cores that communicate with one another through a network-centric architecture using asynchronous or mesochronous communication schemes. In these systems, both parallel and serial links may be used. The parallel data link provides high data rates at the cost of a larger chip area, more routing overhead, and higher dynamic power dissipation. In addition, although the parallel links are utilized only a small portion of the time, they dissipate leakage power at all times. Serial communication schemes alleviate the problems due to fewer wires, line drivers, and repeaters at the expense of a lower data transfer rate, and hence, they should be exploited whenever they do not violate the throughput requirement [4][5].

The data transmission over long links could cross clock domains when multiple clock domains exist. This usually requires some synchronization, which may be realized by injecting a clock into the data stream at the transmitter side and recovering it at the receiver side by using a clock-data recovery (CDR) circuit. The circuit, which often requires a power-hungry PLL, takes a while to converge to the proper clock frequency and phase at the beginning of each transmission. Among other synchronization paradigms, one can refer to globally asynchronous locally synchronous (GALS) scheme [7][8]. In the GALS scheme, every core is a synchronous block with its own local clock. The communication protocol between the cores is asynchronous and makes use of the request and acknowledge signals for the handshaking. Here, the global wires will span along multiple clock domains making the signal transfer

delays equal to multiple clock cycle times. This makes the inter-core communication slow due to the overhead required for the generation and the transfer of the request and acknowledge signals [8].

A variant of the GALS methodology is the mesochronous clocking technique where the handshaking overhead is reduced to only a strobe signal. The mesochronous scheme is typically used for the communication between two cores that have the same clock frequency but with two different phases [9]. The problem with this communication protocol is metastability which may occur if the sampling edge of the clock occurs when the input data is changing [9]. To overcome this problem, several techniques have been suggested in the literature (see e.g., [9]-[11]).

In the serial communication schemes suggested in [4] and [5], the clock frequencies of the transmitter and receiver can be somewhat different. In [4], the transmitter and the receiver have separate ring oscillators that are controlled by a strobe pulse. In this method, the transmitter sends a strobe pulse with every frame of data and a counter controls the number of the receiver clocks in every frame of the data [4]. The method of [5] is similar to that of [4] with this difference that, instead of the counter, a shift-register controls the ring oscillator. This modification improves the speeds of the transmitter and the receiver. In both of these techniques, the frequency of the external clock (strobe) which is sent from the transmitter to the receiver is equal to the number of data frames per second.

In the present work, we introduce two new serial interface schemes for on-chip communications. In the first scheme, the frequency of the strobe signal that is sent from the transmitter to the receiver is equal to half of the number of data frames per second. The second scheme eliminates the strobe signal between the transmitter and the receiver by sending the control and data information on a single serial line (in-band control signal.) The proposed schemes can both be used in NoC's to reduce the complexity of wiring as well increase the spacing between the global wires. The latter operation lowers the effect of the coupling capacitance and reduces the power consumption in the line drivers.

The remainder of the paper is organized as follows. The first scheme with a single strobe serial interface is described in Section 2. The proposed single wire serial interface is explained in Section 3. In Section 4, the serial schemes are extended to wider links between cores in SoC's and Section 5 explains the maximum acceptable tolerance between receiver and transmitter frequency. The power consumption in the serial links and the results are discussed in Section 6 and 7 respectively. Finally, the summary and conclusion are given in Section 8.

II. The Single Strobe Serial (SSS) Interface

In this section, we describe the first proposed scheme for serial communications between two cores on the chip. In the scheme, which is called Single Strobe Serial (SSS) scheme, there are only data and strobe signals between the two cores. Every frame of data has n bits that are transferred serially on the data line. The strobe signal toggles one time for every frame of data (instead of two or more times as in the schemes of [4], [5] and [11]). This reduction in switching activity on the strobe line leads to a power reduction for this line and its line driver and repeaters.

In the transmitter (cf. Figure 1(a)), a ring oscillator is used to generate a serial transfer clock to synchronize the serial transmission of the data. This ring oscillator starts its oscillation after the rising or falling edge of the strobe and generates the transmitter clock, CLK_t . Next, the data is sent on the link by shifting out the content of a shift register by CLK_t (a parallel-to-serial converter). Therefore, the edge of the first bit of data in the transmitter occurs after the edge of the strobe. Since the lengths of the data and the strobe lines are approximately the same, the data and the strobe signals will have nearly equal propagation delays on the links between the two cores. Therefore, the strobe signal reaches the receiver in receiver ring oscillator, which subsequently generates the receiver clock, CLK_r . If the receiver clock generator is the same as the transmitter clock generator, then the edge of the first bit of data in the receiver and the rising edge of CLK_r shall roughly occur at the same time whereas, for proper sampling of received data, the falling edges of CLK_r occur in the middle of the data bit duration.

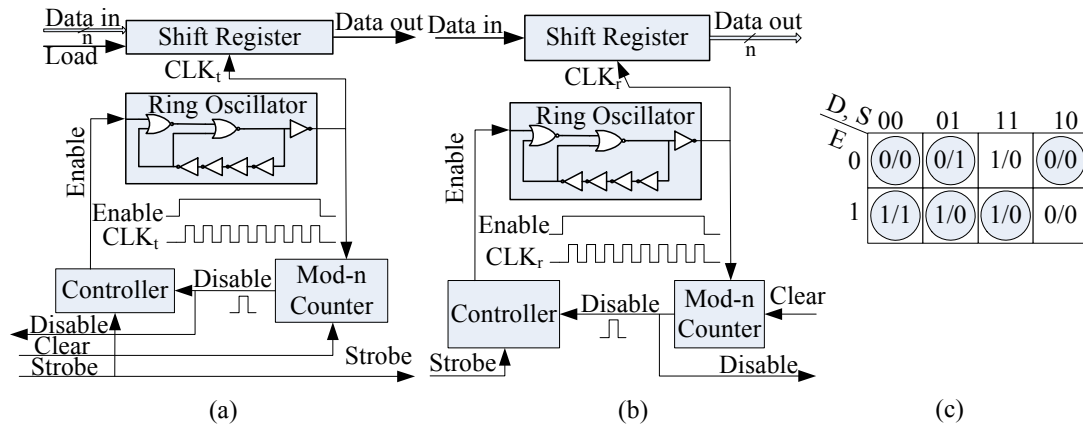


Figure 1 a) Block diagrams of the SSS transmitter b) Block diagrams of the SSS receiver c) Transition table of the controller. D: disable input, S: strobe input, E: enable output.

The transmitter and the receiver require a controller and a binary counter to generate the proper signal for the enable input of their respective ring oscillators. The counter counts the number of clocks generated

by the ring oscillator and when the desired number of clock cycles are generated, it clears the output of the controller (disables the ring oscillator). The controller sets its output (enable signal) to ‘1’ at both the rising and the falling edges of the strobe input and resets its output to ‘0’ at the rising edge of the disable input. The controller, whose transition table is depicted in Figure 1(c), does nothing at the falling edge of the disable input. On the transmitter side, before transmission of an n-bit frame, the block that generates the frame also produces a clear pulse (on the *Clear* line of the transmitter) when the frame is ready. This pulse resets the transmitter counter to prepare it for the data frame transmission. Similarly, on the receiver side, after reception of an n-bit frame, the block that consumes the received frame also produces a clear pulse (on the *Clear* line of the receiver) when it has registered the received frame. This resets the receiver counter to make it ready for a new frame reception. The complete waveforms of the transmitter side of the SSS scheme have shown in Figure 2. As is evident from the figure, the data is transferred on the data line after the strobe signal’s rising or falling edge. As mentioned earlier, the strobe signal reaches the receiver earlier than the data by an amount equal to $t_{strobe \rightarrow data}$. The strobe signal enables the clock generator at the receiver and a shift register samples the data line at every clock of the receiver clock generator (CLK_r). If the receiver clock generator is the same as the transmitter clock generator, the frequencies of CLK_r and CLK_t are equal. Referring to Figure 1 and Figure 2, we may write

$$t_{strobe \rightarrow data (rec)} = t_{strobe \rightarrow enable} + t_{enable \rightarrow clk} + t_{clk \rightarrow data} + t_{line} \quad (1)$$

$$t_{strobe \rightarrow clk (rec)} = t_{line} + t_{strobe \rightarrow enable} + t_{enable \rightarrow clk} \quad (2)$$

$$\Delta t = t_{strobe \rightarrow data (rec)} - t_{strobe \rightarrow clk (rec)} = t_{clk \rightarrow data} \quad (3)$$

where

$t_{strobe \rightarrow data (rec)}$ denotes the delay from the edge of Strobe at the transmitter to the start of the first data bit time at the receiver,

$t_{strobe \rightarrow enable}$ is the delay from the edge of Strobe to the edge of Enable in the Controller (Figure 1(a)),

$t_{enable \rightarrow clk}$ denotes the delay from the edge of Enable to the edge of the first clock of Ring Oscillator,

$t_{clk \rightarrow data}$ is the delay from the edge of the first clock to the start of the first data bit time in Figure 1(a) (Shift Register),

t_{line} corresponds to the delay of the data and the Strobe interconnect lines, and finally,

$t_{strobe \rightarrow clk}$ is the delay from the edge of Strobe at the transmitter to the edge of the first clock at the receiver.

Notice that we add a delay (equal to Δt or $t_{\text{clk} \rightarrow \text{data}}$) on the Strobe to the Clk_r path in the receiver (for example in the output of controller) to adjust the rising edge of the first pulse of Clk_r on the start of the first data bit time at the receiver. Therefore, the falling edges of the Clk_r , which occur in the middle of the data bit duration, must be used as the falling edge of the clock for sampling the data line in the receiver. After receiving a complete frame of the data, the disable signal is asserted to stop the ring oscillator. Finally, the output port reads the data from the receiver shift register, activates the clear signal, and prepares the receiver for receiving the next data frame.

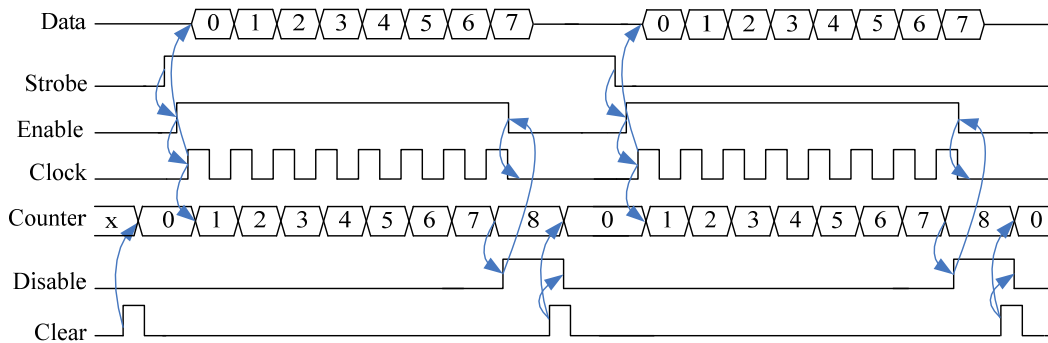


Figure 2. Timing waveforms for various data and control signals for the proposed SSS scheme (transmitter side).

III. The Single Wire Serial (SWS) Interface

In this section, we describe the proposed in-band Single Wire Serial interface (SWS) scheme for serial communication between two cores. The scheme makes use of only one line for communicating both data and control signals between the two cores. Every frame of data (containing control signals) has $(n + 2)$ bits, including a start-bit ('1'), n bits of data, and a stop-bit ('0'), which are transferred serially on the serial line. Every data frame is started with the start bit, which plays the role of the strobe signal for initiating the sampling of the data at the receiver.

The transmitter reads n -bit data words from an input buffer and then makes the $(n + 2)$ bit frame by adding the start and the stop bits at the start and the end of the data word, respectively. Each frame is transferred on the serial line (Data Line) by shifting right the bits in $(n + 2)$ consecutive clock cycles of the transmitter ring oscillator. When the positive edge of the start bit is detected by the receiving core, a ring oscillator in the receiver is enabled to generate the receiver clock. Then the serial line is sampled at the positive edge of the receiver clock signal and after n clock cycles, the receiver ring oscillator is

disabled. Therefore, the n bits of the data (without the start and the stop bits) are sampled and stored in an output buffer. Two separate ring oscillators, whose circuits are the same, generate the clocks for the transmitter and the receiver. Hence, the frequencies of the clocks should theoretically be the same. The same ring oscillator as shown in Figure 1 is used here.

A. Transmitter

The operation of the transmitter, whose block diagram is shown in Figure 3(a), is initiated by using a starter (RS flip-flop) when some data words are ready in the input buffer and is stopped when the last data word is transmitted and the input buffer has become empty. Before any transmission, the output of the starter is zero, the ring oscillator is disabled, and $(n + 2)$ bit ring counter is in the reset state. Thus, only the LSB output of the ring counter (q_0) is '1'. When the first data-word is loaded in the input buffer, the output of the starter becomes active thereby enabling the ring oscillator. At the positive edge of the first clock, an $(n + 2)$ bit data frame will be loaded in the transmitter shift register. Then, in the next $(n + 1)$ clocks, the transmitter shift register shifts out the data frame bit by bit. The ring counter rotates right too. After $(n + 2)$ clock cycles, the stop bit is transferred on the serial line and q_0 will become '1'. At this time, if the input buffer is empty, the ring oscillator will be disabled and the serial line will go into the zero state (the parking mode). Otherwise, the next data word will be read from the input buffer and loaded into the shift register at the next positive edge of the clock. Therefore, the data transmission of an n -bit real data in $n + 2$ clock cycles continues without any interruption.

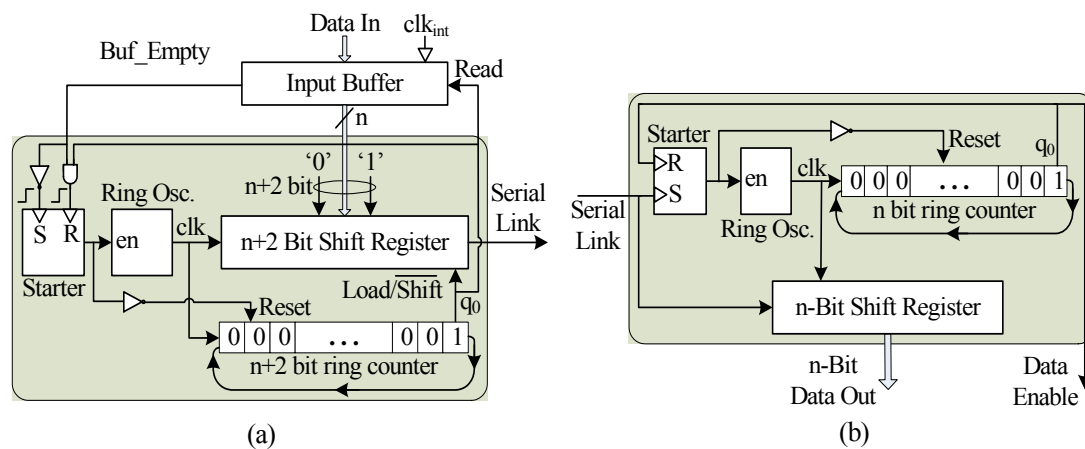


Figure 3 The block diagram of a) the SWS transmitter b) the SWS receiver.

B. Receiver

The operation of the in-band SWS serial receiver, whose block diagram is depicted in Figure 3(b), is initiated using a starter (RS flip-flop) when a low-to-high (low is due to the stop bit of the previous frame and high is from the start bit of the current frame) transition occurs on the input serial line. After being enabled, the receiver reads an n -bit data word from the input line during the next n consecutive clocks. The starter is reset before receiving a new data frame. Before the first low-to-high transition on the input serial line, the output of the starter is zero, the ring oscillator is disabled, and the n -bit ring counter is in the reset state while only q_0 is '1'. The first low-to-high transition on the input serial line changes the starter output to the high state, thereby enabling the receiver ring oscillator. Subsequently, in the next n consecutive clocks, the receiver shift register is shifted right bit by bit receiving the data from the input serial line while the ring counter rotates right. Therefore, after n clock cycles, a complete n -bit data word will be ready on the parallel output data lines while the LSB output of ring counter (q_0) will become '1'. Finally, the starter is reset, thereby disabling the receiver ring counter and the n -bit parallel data is loaded into an output buffer. At this time, the receiver becomes ready for receiving the next start of frame (low-to-high transition on the input serial line).

IV. Parallel SSS and SWS Interfaces

The proposed SSS and SWS schemes may be utilized in parallel communication or wider link schemes between cores in NoC's. For this purpose, we only need to use several shift registers in the transmitter with the same control circuits. In the destination, every serial line must have a separate receiver to eliminate jitter and mismatch between the parallel lines. In this case, the received data will be valid when all the Data Enable signals in the receivers become active. The block diagram of a 4-bit transmitter with the SWS scheme is shown in Figure 4 where we load the LSB of all shift registers with '1' (start bit). Similarly, one can extend the serial SSS transceiver to the parallel SSS one.

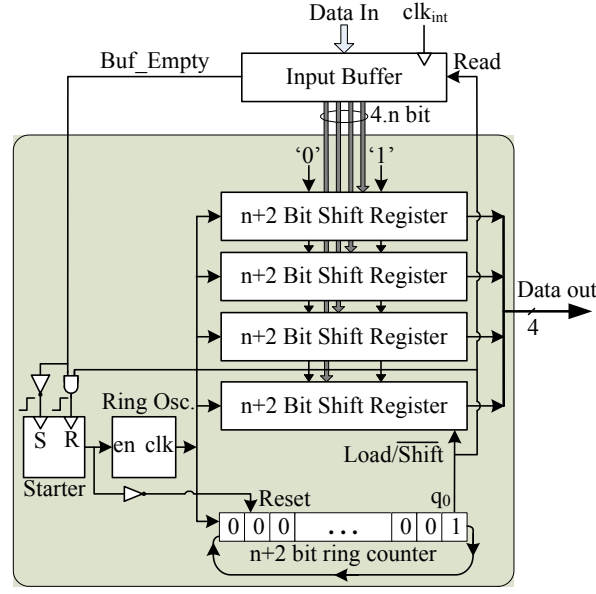


Figure 4. The block diagram of the proposed SWS scheme for a 4-bit parallel bus.

V. Tolerance to Frequency Difference between the Receiver and the Transmitter

In the SSS structure, we add a small delay in the clock path of the receiver shift register to adjust the first negative edge of the receiver clock in the middle of the first data bit time. Next, we must ensure that the edge of the last receiver clock does not occur in the failure zone. Figure 5 shows these conditions where in Figure 5(a) (Figure 5(b)), the frequency of the receiver ring oscillator is lower (higher) than the frequency of the transmitter ring oscillator. In both of these cases, all the negative edges of the receiver clock cycles are in the proper region. In this figure, t_s and t_h are the setup and hold times of the receiver shift register. The same figures may be used for the SWS scheme, except that in this case we adjust the first positive edge of the receiver clock in the middle of the first data bit time. Referring to the figure, the condition for error free sampling in the receiver may be expressed as

$$nT - t_h > (n - 1/2)T_{\max} \quad (4)$$

$$(n - 1)T + t_s < (n - 1/2)T_{\min} \quad (5)$$

where n is number of bits per frame. Using these inequalities, one may write

$$f_{r,\min} < f_r < f_{r,\max} \quad (6)$$

where

$$f_{r,\min} = \frac{(n-1/2)f_t}{n-t_h f_t} \quad (7)$$

$$f_{r,\max} = \frac{(n-1/2)f_t}{n-1+t_s f_t} \quad (8)$$

Here, $f_t (= 1/T)$ and f_r are the clock frequencies of the transmitter and the receiver, respectively. These equations show in our schemes we can have some frequency mismatching between transmitter and receiver. The maximum acceptable mismatching is depended to the length of frames (n) and we can have higher mismatching for smaller value of n .

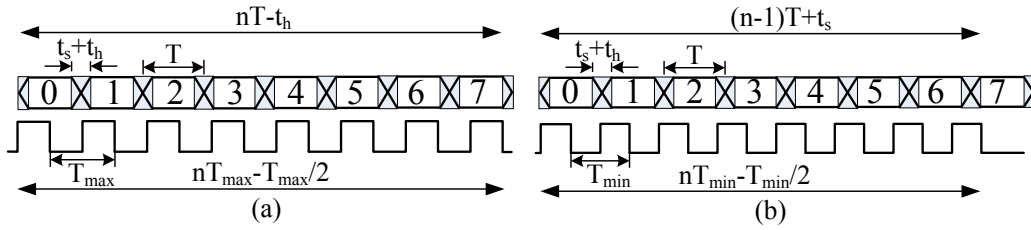


Figure 5 Timing diagram of the receiver. (a) The receiver ring oscillator is slower than the transmitter ring oscillator. (b) The receiver ring oscillator is faster than transmitter ring oscillator.

VI. Power Dissipation Analysis

The total interconnect capacitance per unit length C_t can be modeled as [13][14]

$$C_t = (\alpha C_g + (MCF_l + MCF_r) C_c) \quad (9)$$

where C_g is the line-to-ground capacitance per unit length and C_c is the coupling capacitance per unit length between two neighboring lines. The switching factor of C_g , that is α , is 1 for the top layer interconnects and 2 for the intermediate layer interconnects because there are two metal layers above and below any line of the intermediate layer interconnects. Assuming each interconnect is only coupled to its nearest neighbors, MCF_l and MCF_r are the Miller coupling factor between the line of interest and its left and right neighboring lines and it depends on their relative switching activity as stated here. The factor is 2, 1, and 0 for two oppositely switching neighboring lines, only one line switching while the other is quiet, and for two similarly switching neighboring lines, respectively. If the transitions are uniformly distributed $MCF_{av} = 1$ [13]. Hence, the average energy dissipation per unit length of an interconnect per transition, E_{av} , is given by

$$E_{av} = 0.5C_{t,av}V_{DD}^2 \quad (10)$$

where $C_{t,av}$ is the average capacitance and VDD is the supply voltage.

The line-to-ground and the coupling capacitance per unit length of an interconnect line on a ground plane or top layer interconnect can be modeled by Equations (1) and (2) of [15] while the resistance and the inductance per unit length of an interconnect line have been modeled in [14]. The ITRS projections of the interconnects for different technologies may be found in [16]. Using the results presented in these references, we can calculate the parasitic capacitances, resistance, and inductance of interconnect lines. The result of these calculations show that the total interconnects capacitance per unit length (C_t) does not decrease while the average length of global interconnects increases with process technology scaling. Therefore, the power consumption of interconnections increases with the technology scaling. In contrast, power consumption per logic gate decreases with technology scaling.

In the SSS scheme, we reduce the switching activity on the control line, resulting in a significant improvement in the interconnect energy dissipation while in the SWS scheme, we reduce the number of bus lines from two to one. Therefore, for the same bus area, the reduction in the number of bus lines can lead to larger interconnect space (and/or width). Larger interconnect space reduce the coupling capacitance, while wider interconnects reduce the line resistivity, leading to a significant improvement in the interconnect energy dissipation and delay. The reduction in the delay can be transformed into a further energy savings by reducing the number and size of the required repeaters. This improvement increases as the technology scales.

Using a distributed model for top layer interconnects (we assume that the top layer is used for inter-core communication lines), the energy dissipation per transition per unit length of any interconnect can be calculated by Equations (9) and (10) with $\alpha = 1$ and $MCF_l = MCF_r = 1$. Therefore, the energy dissipation per unit length in the SSS and SWS serial link per a frame of data may be expressed as

$$E_{av,SSS} = 0.5(C_g + 2.C_c).V_{DD}^2(SA_{data} + SA_{strobe}) \quad (11)$$

$$E_{av,SWS} = 0.5(C_{g2} + 2.C_{c2}).V_{DD}^2.SA \quad (12)$$

In this equation, C_{g2} and C_{c2} are the line-to-ground and coupling capacitance per unit length of an interconnect layer on a ground plane in a SWS serial link, respectively. One can show that for 8-bit random data frames, the average switching activity (SA) value of a SWS scheme is 5.5 while the sum of the average values of the data and control (strobe) switching activities ($SA_{data} + SA_{control}$) in three different 2-wire serial links, namely, scheme of [4], scheme of [5], and SSS schemes are 6, 6, and 5, respectively. The parasitic capacitances of SWS scheme calculated from [15] are presented in Table I. The normalized

energy dissipation per unit length per 8-bit random data frame transmission for four different serial link schemes are reported in

Table II. These results show that the SSS and SWS schemes are more efficient than the schemes of [4] and [5].

Table I. Parasitic capacitance of SWS interconnect.

Technology (nm)	130	90	65	45	32	22
C_c	45	46	48	41	36	34
C_g	45	43	42	34	29	25
$C_t = C_g + 2.C_c$	135	135	138	116	101	93

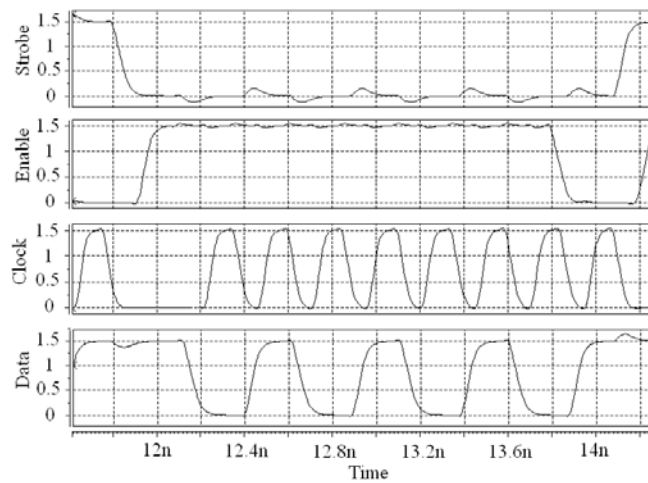
Table II. Comparison of normalized energy dissipation per unit length per 8-bit data frame transmission.

Technology (nm)		130	90	65	45	32	22
V_{DD} (V)		1.3	1.2	1.1	1	0.9	0.8
Energy (pj/mm)	Scheme of [4]	1	0.87	0.75	0.53	0.36	0.27
	Scheme of [5]	1	0.87	0.75	0.53	0.36	0.27
	SSS	0.83	0.72	0.62	0.44	0.3	0.23
	SWS	0.62	0.53	0.45	0.32	0.22	0.16

VII. Experimental Results

To evaluate the performance of the SSS and the SWS transceivers, the complete circuits shown in Figure 1 and Figure 3 were simulated at the transistor level (with HSpice) by using a 0.13 μ m standard CMOS technology [14]. The simulations were performed for serial and 4-bit parallel buses for 8-bit frames. Fig. 6(a) shows the waveforms of the data, the strobe, the clock, and the enable of the ring oscillator at the receiver of the SSS serial bus. In this figure, the receiver reads the sequence of “10101010”. The results show that the transmitter and the receiver can operate up to a clock frequency of 4.05GHz. In eight successive clocks, the 8-bit input shift register shifts right bit-by-bit to read the received data from the serial input line while in the ninth clock cycle, the received data is loaded into the receiver buffer. Next, the receiver can start a new reception of data. When the receiver is reading new data from the serial line, the previous received data can be transferred into the next stage without any metastability error. Therefore, the transmission bandwidth will be 3.6Gbps (= 4.05GHz \times (8/9)) or 450MBps with 8-bit frames on the serial bus. If a 4-bit parallel bus is used, the bandwidth increases to 1.8GBps.

To evaluate the performance of the SWS transceiver, we use an input (output) buffer with 16 8-bit registers. Fig. 6(b) shows the HSpice simulation results for the waveforms of the enable signal of the ring oscillator (Ring Enable), the Serial Line, the clock (Receiver Clock), and the LSB of the ring counter (q_0) at the receiver for one data frame of “01010101”. The results show that the transmitter and the receiver can operate with a clock frequency up to 5.36GHz. The effective data transmission rate (excluding stop and start bits) is about 4.288Gbps, which is equivalent to 536MBps per serial line. In another simulation, we loaded the input buffer with 16 data words as 11h, 22h, 33h, 44h, ... FFh, and 00h, and transmitted these data words serially. The receiver block received these data and stored them in the output buffer. Fig. 6(c) shows the output waveforms of the output buffer (8-bit parallel outputs) where the transmission frequency of 4.8 GHz was used.



(a)

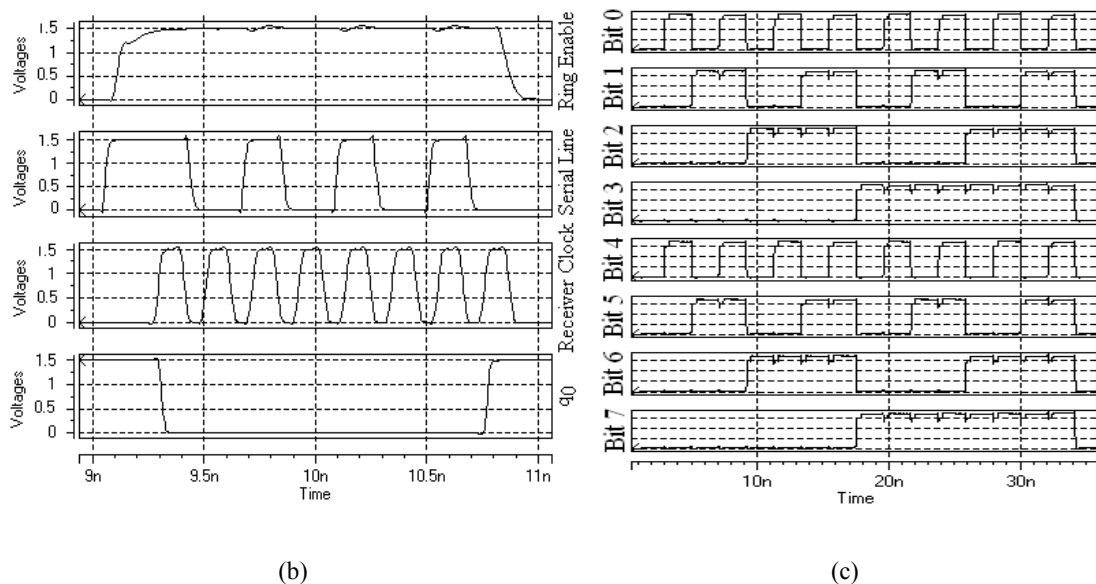


Fig. 6 a) waveforms of the SSS transmitter b) waveforms of the SWS transmitter c) Output waveforms of the receiver buffer in the SWS scheme.

To assess the effect of the number of bits per frame (N) to the amount of the tolerable frequency mismatch between the transmitter and receiver, we used Equations (7) and (8) to obtain the minimum and maximum frequencies of the receiver assuming t_s and t_h to be both equal to zero. The results, which are reported in Table III, show that as the number of bits increases, the receiver frequency tolerance decreases.

Table IV shows the permissible range of the receiver frequency calculated using Equations (7) and (8) as well as simulations for the case where the transmitter frequency (f_t) were 4GHz and 1.8GHz. Note that simulations of the designs used in this study led to the set-up time (t_s) and hold time (t_h) of 60 and 50ps, respectively. The simulation results given in the table show that we can have about $\pm 3.8\%$ and $\pm 6.1\%$ tolerances in the receiver frequency, respectively.

Table III. The permissible range of the receiver frequency.

N	4	8	9	10
$f_{r,\min}$	0.875	0.938	0.945	0.95
$f_{r,\max}$	1.166	1.071	1.063	1.055
Acceptable tolerance	12.5%	6.2%	5.5%	5%

Table IV. Calculated and Simulated values of the permissible range of receiver frequency.

f_i (GHz)	f_r (max)		f_r (min)	
	Calculated	Simulated	Calculated	Simulated
1.8	1.9	1.91	1.71	1.68
4	4.17	4.19	3.87	3.85

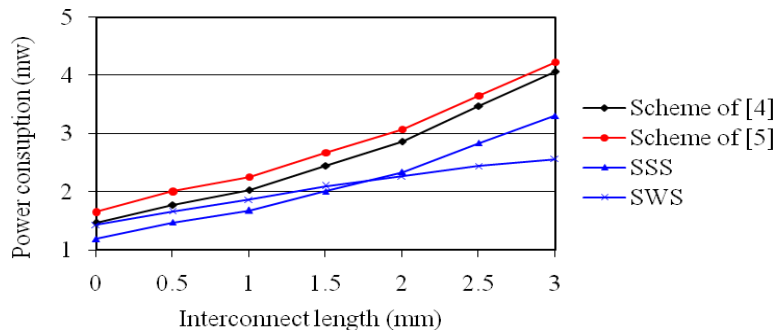
We also simulated the two schemes that have been proposed in [4] and [5] at the transistor level by using the same 0.13 μm standard CMOS technology and compared them with our schemes. Table V which shows the number of transistors, maximum frequency and bandwidth for implementing the different communication schemes reveals that the transistor count for the SSS (SWS) scheme is 7% (11%) and 8% (9%) lower (more) than those of schemes in [4] and [5], respectively. The maximum bandwidths of SSS (SWS) is 32% (55%) and 23% (45%) faster than the schemes of [4] and [5], respectively.

Table V. Complexity and performance of different schemes.

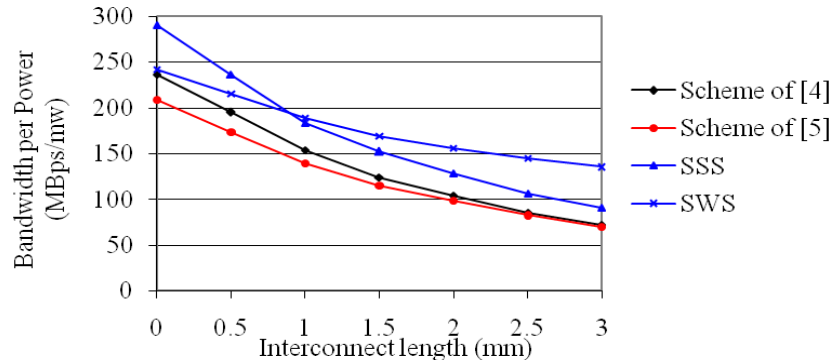
	Number of transistor			Performance (GHz, MBps)	
	Transmitter	Receiver	Total	Maximum Frequency	Maximum Bandwidth
Scheme of [4]	252	174	426	3.22	345
Scheme of [5]	285	146	431	3.41	370
SSS Scheme	206	190	396	4.05	435
SWS Scheme	257	214	471	5.36	536

We calculated the power consumptions of different schemes at 345MBps, which all of the schemes can operate at for different lengths of interconnect (without any repeaters) by HSpice. Experimental results are shown in Figure 7(a). These results show that although the SSS scheme consumes more power than the schemes of [4] and [5] at the maximum frequency (or bandwidth), but for the same bandwidth it consumes less power. The lower power consumption is expected due to the lower switching activity on the strobe line of the SSS scheme. As Figure 7(a) reveals, the power consumption of the SWS scheme is much lower than those of other schemes especially for longer interconnects. For an interconnect with the length of 3mm, at the bandwidth of 345MBps, the power consumption of the SWS (SSS) scheme is about 37% (19%) and 39% (22%) lower when compared to those of schemes in [4] and [5], respectively.

Figure 7(b) shows the bandwidths per unit power consumption of different transceivers at 345MBps. This figure shows that the bandwidth of the SSS scheme at 345MBps is 21% (23%) and 35% (28%) more than those of schemes in [4] and [5], respectively, for 1mm (3mm) interconnect layers. The bandwidth improvement of SWS scheme relative to the schemes of [4] and [5] for 1mm (3mm) interconnect layers is 9% (59%) and 21% (65%), respectively. This figure shows that for interconnects longer than 1mm, the SWS scheme is the best communication scheme while for interconnects shorter than 1mm, the SSS scheme is the best one.



(a)



(b)

Figure 7 a) Power consumption at 345MBps b) Bandwidth per power consumption for different schemes at 345MBps.

VIII. Conclusion

In this paper, two serial communication schemes for the communication over serial buses in a network on chip were presented. The techniques, called SSS and SWS, removed the metastability errors in the mesochronous communications. In both methods, the transmitter and the receiver had separate clock

generators with the same circuitry. The schemes allowed that the transmitter and receiver to have some tolerable frequency differences. In the first method, a strobe line was used to activate the oscillators. Local counters were used to count the number of bits in the data frame and to stop the local oscillators when the frame is processed. In the second method, a single physical line was used to transmit both data and control information. The data transmission was controlled by the output of a flip-flop, indicating the empty/full state of an input buffer whereas the data reception is controlled by decoding a '1' start bit and a '0' end bit which have been added to the n -bit data word to form a frame. Both schemes can be used for parallel buses without any change in the control circuits. Results of HSpice simulations in a 0.13 μ m standard CMOS technology showed that the maximum bandwidths of the schemes were considerably higher than those of the previously proposed techniques in the literature. These techniques also showed considerable power savings especially as the interconnect lengths are increased. Our simulation results showed that the maximum bandwidth of SSS and SWS schemes were 3.6Gbps and 4.288Gbps that were 32% (23%) and 55% (45%) higher than the scheme of [4] ([5]). For 3mm interconnects, at 345MBps bandwidth, the power saving in the SWS and SSS schemes were 37% (39%) and 19% (22%) relative to scheme of [4] ([5]).

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References

- [1] International Technology Roadmap for Semiconductors (ITRS 2003) (<http://public.itrs.net/>).
- [2] D. Bertozzi and L. Benini, "Xpipes: A Network-on-Chip Architecture for Gigascale Systems-on-Chip," *IEEE Circuit and Systems Magazine*, Second Quarter 2004, pp.18-31.
- [3] L. Benini and G. De Micheli, "Network on Chips: A New SoC Paradigm," *IEEE Computer*, Jan. 2002.
- [4] S. Kimura, T. Hayakawa, T. Horiyama, M. Nakanishi, and K. Watanabe, "An On-Chip High Speed Serial Communication Method Based on Independent Ring Oscillators," *in the Proceedings of The IEEE International Solid-State Circuits Conference (ISSCC 2003)*, 2003, pp. 390-391.

- [5] I. C. Wey, L. H. Chang, Y. G. Chen, S. H. Chang, and A. Y. Wu, "A 2Gb/s High-Speed Scalable Shift-Register Based On-Chip Serial Communication Design for SoC Applications," in *the Proceedings of The IEEE International Symposium on Circuits and Systems, ISCAS 2005*, 23-26 May 2005, Vol. 2, pp.1074 – 1077.
- [6] H. Kaul, and D. Sylvester, "Low-Power On-Chip Communication Based on Transition-Aware Global Signaling (TAGS)," *IEEE Transaction on Very Large Scale Integration (VLSI) Systems*, Vol. 12, No. 5, May 2004, pp. 464-476.
- [7] E. Beigné, F. Clermidy, P. Vivet, A. Clouard, and M. Renaudin, "An Asynchronous NOC Architecture Providing Low Latency Service and its Multi-level Design Framework," in *the Proceedings of The 11th IEEE International Symposium on Asynchronous Circuits and Systems (ASYNC'05)*, 2005.
- [8] J. Teifel and R. Manohar, "A High-Speed Clockless Serial Link Transceiver," in *the Proceedings of The 11th IEEE International Symposium on Asynchronous Circuits and Systems (ASYNC'03)*, 2003, pp. 151-161.
- [9] F. Mu and C. Svensson, "Self-Tested Self-Synchronization Circuit for Mesochronous Clocking," *IEEE Transaction on Circuits and Systems*, vol. 48, no. 2, Feb. 2001, pp. 129-140.
- [10] I. Söderquist, "Globally Updated Mesochronous Design Style," *IEEE Journal of Solid-State Circuits*, vol. 38, no. 7, July 2003, pp. 1242-1249.
- [11] B. Mesgarzadeh, C. Svensson, and A. Alvandpour, "A New Mesochronous Clocking Scheme for Synchronization in SoC," in *the Proceedings of The IEEE Int. Symposium on Circuit and Systems (ISCAS04)*, 23-26 May 2004, vol. 2, pp. II - 605-608.
- [12] S. J. Lee, K. Kim, H. Kim, N. Cho, and H. J. Yoo, "Adaptive Network-on-Chip with Wave-Front Train Serialization Scheme," in *the proceeding of Symposium on VLSI Circuits Digest of Technical Papers*, 2005, pp.104-107.
- [13] M. Ghoneima, Y. Ismail, M. Khellah, J. Tschanz, and Vivek De, "Serial-Link Bus: A Low-Power On-Chip Bus Architecture," in *the proceeding of International Conference on Computer-Aided Design, ICCAD-2005*. Nov. 6-10, 2005, pp. 541 - 546.
- [14] Predictive Technology Model (PTM), Available on-line: <http://www.eas.asu.edu/~ptm>.

- [15] S-C. Wong, G-Y. Lee, D-Y. Ma, "Modeling of Interconnect Capacitance, delay and crosstalk in VLSI," *IEEE Transaction on Semiconductor Manufacturing*, vol. 13, no. 1, Feb. 2000, pp. 108-111.
- [16] S. Im, N. Srivastava, K. Banerjee, and K. E. Goodson, "Scaling Analysis of Multilevel Interconnect Temperatures for High-Performance ICs," *IEEE Transactions on Electron Devices*, vol. 52, no. 12, Dec. 2005, pp. 2710-2719.